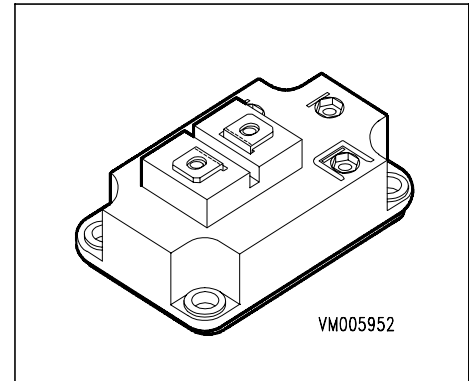


Diode Power Module

Preliminary data

- Inside fast free-wheeling diode
- Package with insulated metal base plate
- Diode especially for brake choppers
- matched with BSM 300 GA 170 DN 2 E 3166



Type	V_{R25}	I_{FDC}	Package	Ordering Code
BYM 600 A 170 DN2	1700V	600A	SINGLE DIODE 1	C67070-A2902-A67

Maximum Ratings

Parameter	Symbol	Values	Unit
Diode reverse voltage $T_j = 25\text{ °C}$	V_{R25}	1700	V
DC current $T_C = 25\text{ °C}$ $T_C = 80\text{ °C}$	I_{FDC}	600 400	A
Pulsed diode current, $t_p = 1\text{ ms}$ $T_C = 25\text{ °C}$ $T_C = 80\text{ °C}$	I_{Fpuls}	1200 800	
i^2t -value, $t_p = 10\text{ ms}$ $T_j = 0\text{ °C}$	$\int i^2 t$	96800	A ² s
Power dissipation per diode $T_C = 25\text{ °C}$	P_D	1400	W
Chip temperature	T_j	+ 150	°C
Storage temperature	T_{stg}	-55 ... + 150	
Thermal resistance, chip case	R_{thJC}	≤ 0.09	K/W
Insulation test voltage, $t = 1\text{ min.}$	V_{is}	4000	Vac
Creepage distance	-	20	mm
Clearance	-	11	
DIN humidity category, DIN 40 040	-	F	sec
IEC climatic category, DIN IEC 68-1	-	55 / 150 / 56	

Electrical Characteristics, at $T_j = 25\text{ °C}$, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	

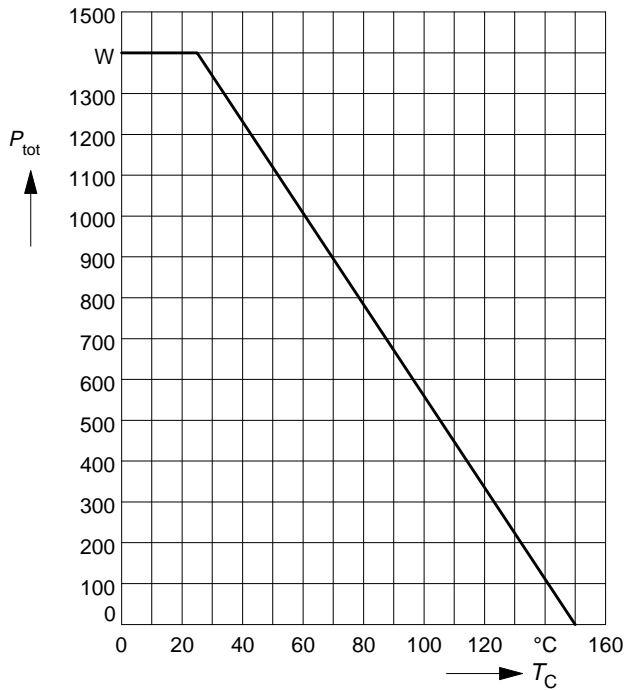
Free-Wheel Diodes

Diode forward voltage $I_F = 300\text{ A}$, $V_{GE} = 0\text{ V}$, $T_j = 25\text{ °C}$ $I_F = 300\text{ A}$, $V_{GE} = 0\text{ V}$, $T_j = 125\text{ °C}$	V_F	-	2 1.8	2.5 -	V
Reverse current $V_{CA} = 1700\text{ V}$, $T_j = 25\text{ °C}$ $V_{CA} = 1700\text{ V}$, $T_j = 125\text{ °C}$	I_R	-	1.1 4.4	1.6 -	mA
Reverse recovery time $I_F = 300\text{ A}$, $V_R = -1200\text{ V}$, $V_{GE} = 0\text{ V}$ $di_F/dt = -1500\text{ A}/\mu\text{s}$, $T_j = 125\text{ °C}$	t_{rr}	-	1	-	μs
Reverse recovery charge $I_F = 300\text{ A}$, $V_R = -1200\text{ V}$, $V_{GE} = 0\text{ V}$ $di_F/dt = -1500\text{ A}/\mu\text{s}$ $T_j = 25\text{ °C}$ $T_j = 125\text{ °C}$	Q_{rr}	-	33 100	- -	μC

Power dissipation

$$P_{\text{tot}} = f(T_C)$$

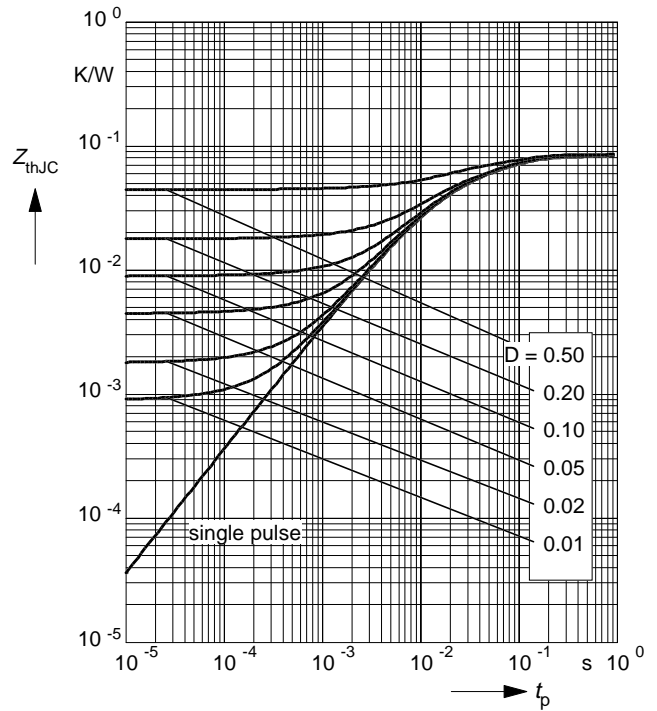
parameter: $T_j \leq 150^\circ\text{C}$



Transient thermal impedance Diode

$$Z_{\text{thJC}} = f(t_p)$$

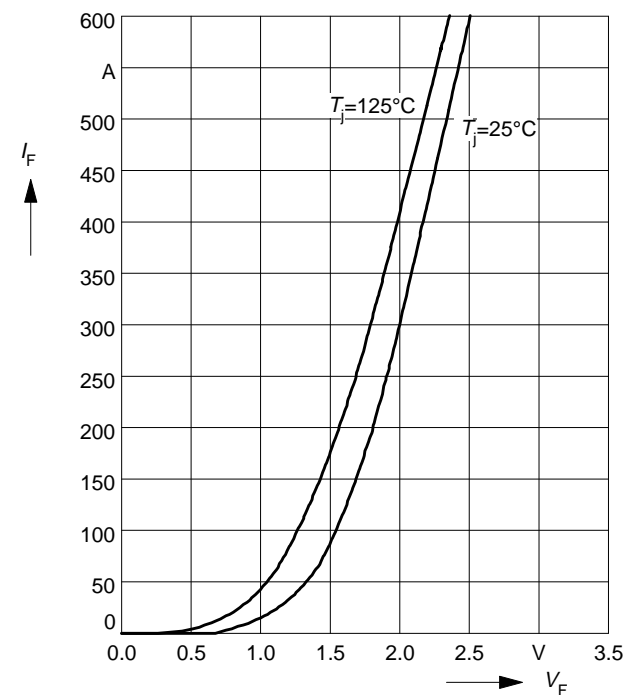
parameter: $D = t_p / T$



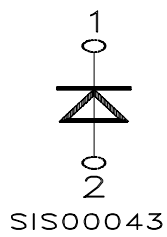
Forward characteristics of fast recovery reverse diode

$$I_F = f(V_F)$$

parameter: T_j



Circuit Diagram



Package Outlines

Dimensions in mm

Weight: 420 g

